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Vishay Siliconix

Dual P-Channel 20 V (D-S) MOSFET

DESCRIPTION

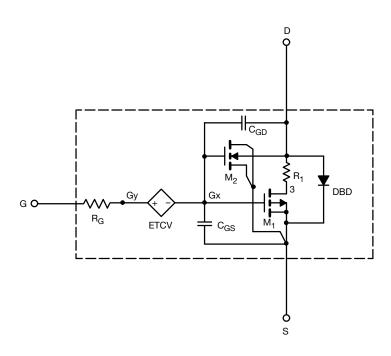
The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model Si5999EDU

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$	1	-	V
Drain-Source On-State Resistance ^a	В	V _{GS} = - 4.5 V, I _D = - 3.5 A	0.047	0.047	Ω
	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 1.5 A	0.077	0.077	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 3.5 A	9	10	S
Diode Forward Voltage	V _{SD}	I _S = - 4 A	- 0.82	- 0.85	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	493	496	pF
Output Capacitance	C _{oss}		142	141	
Reverse Transfer Capacitance	C _{rss}		121	121	
Total Gate Charge	0	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -5 \text{ A}$	12.4	13.2	nC
	Q_g		6.4	6.9	
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5 \text{ A}$	1.6	1.6	
Gate-Drain Charge	Q _{gd}] [1.8	1.8	

Notes

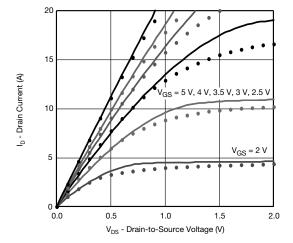
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

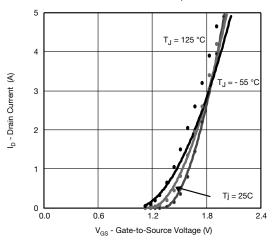


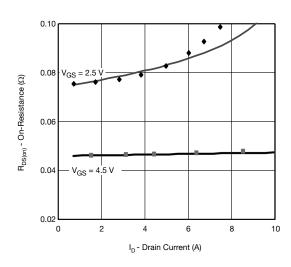
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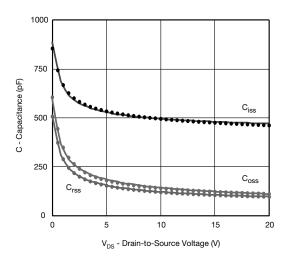
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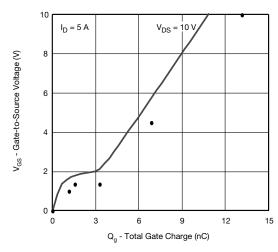
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25 \, ^{\circ}\text{C}$, unless otherwise noted)

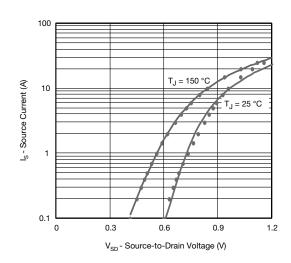












Note

· Dots and squares represent measured data.





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